



# Technical Data

## PST MT800

### SINGLE THYRISTOR MODULE

#### Features:

- Electrically isolated base plate
- High surge capability
- Precious metal pressure contact

#### Typical applications:

- DC motor control (e.g. for machine tools)
- Temperature control (e.g. for ovens, chemical processes)
- Professional light dimming (e.g. for studios, theaters)

#### ELECTRICAL CHARACTERISTICS AND RATINGS

##### Reverse blocking - Off-state

| Device Type | $V_{RRM}$ (1) | $V_{DRM}$ (1) | $V_{RSM}$ (1) |
|-------------|---------------|---------------|---------------|
| PST MT800   | 1800 V        | 1800 V        | 1900 V        |

$V_{RRM}$  = Repetitive peak reverse voltage

$V_{DRM}$  = Repetitive peak off-state voltage

$V_{RSM}$  = Non repetitive peak reverse voltage (2)

|   |                    |                    |
|---|--------------------|--------------------|
| Repetitive reverse and off-state peak leakage current | $I_{RRM}, I_{DRM}$ | 70 mA (3)          |
| Critical rate of rise of off-state voltage            | $dv/dt$            | 500 V/ $\mu$ s (4) |

Notes:

All ratings are specified for  $T_j = 25^\circ\text{C}$  unless otherwise stated.

(1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range -40 to +125  $^\circ\text{C}$ .

(2) 10 ms max. pulse width

(3) Maximum value for  $T_j = T_{jmax}$

(4) Min. value for linear and exponential wave shape to 67% rated  $V_{DRM}$ . Gate open.  $T_j = T_{jmax}$

##### Conducting

| Parameter                                 | Symbol       | Min | Max   | Typ | Unit              | Conditions   |
|---|--------------|-----|-------|-----|-------------------|--|
| Average value of on-state current         | $I_{T(AV)}$  |     | 800   |     | A                 | 50 Hz sine wave, 180° conduction, $T_c = 85^\circ\text{C}$     |
| RMS value of on-state current             | $I_{T(RMS)}$ |     | 1256  |     | A                 | 50 Hz sine wave, 180° conduction, $T_c = 85^\circ\text{C}$     |
| Surge non repetitive current              | $I_{TSM}$    |     | 30    |     | kA                | 50 Hz sine wave<br>Half cycle<br>$V_R = 0$<br>$T_j = T_{jmax}$ |
| $I^2 t$                                   | $I^2 t$      |     | 4500  |     | kA <sup>2</sup> s |  |
| Peak on-state voltage                     | $V_{TM}$     |     | 1.19  |     | V                 | On-state current 2000 A, $T_j = T_{jmax}$                      |
| Threshold voltage                         | $V_{T(TO)}$  |     | 0.83  |     | V                 | $T_j = T_{jmax}$   |
| On-state slope resistance                 | $r_T$        |     | 0.178 |     | $m\Omega$         | $T_j = T_{jmax}$   |
| Holding current                           | $I_H$        |     |       | 350 | mA                | $T_j = 25^\circ\text{C}$                                       |
| Latching current                          | $I_L$        |     |       | 800 | mA                | $T_j = 25^\circ\text{C}$                                       |
| Critical rate of rise of on-state current | $di/dt$      |     | 200   |     | A/ $\mu$ s        | $I_G = 5 I_{GT}$ , $t_r = 1 \mu\text{s}$ , $T_j = T_{jmax}$    |
| RMS isolation voltage                     | $V_{INS}$    |     | 4500  |     | V                 | AC 50 Hz, 60 s   |

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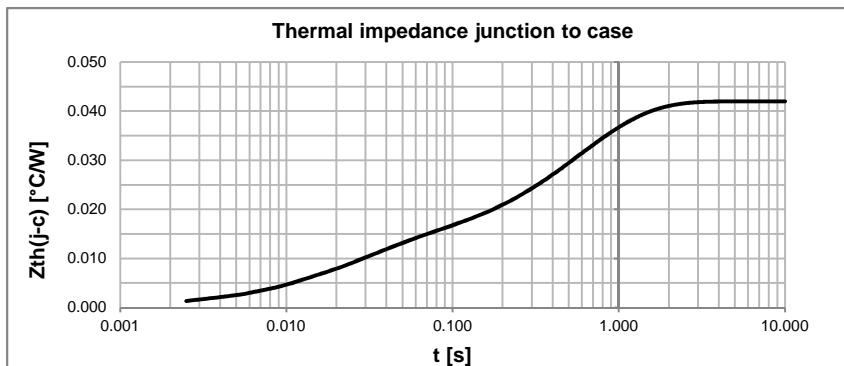
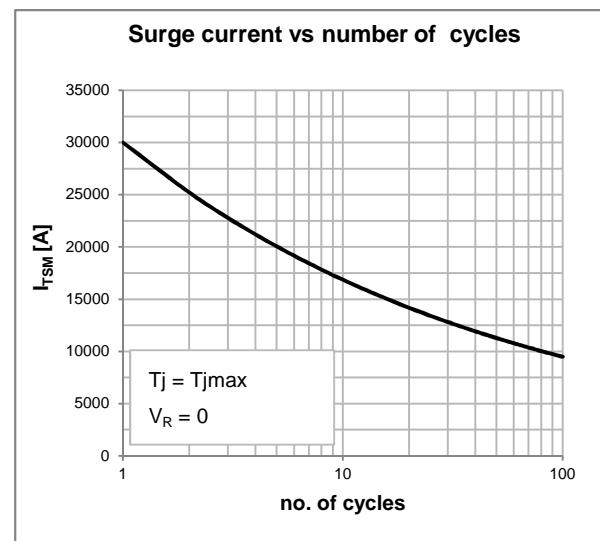
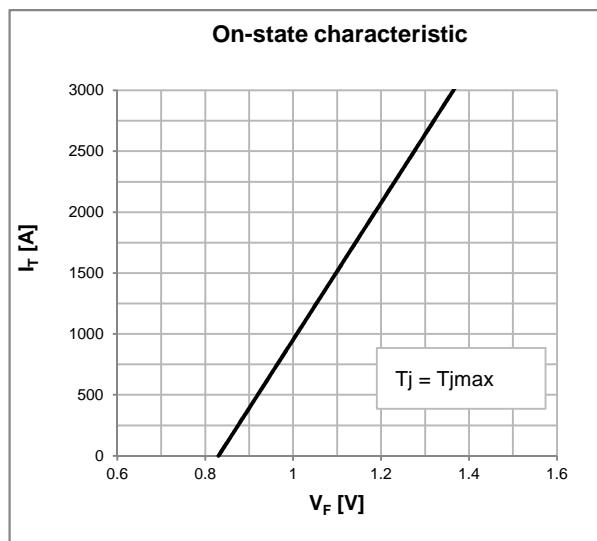
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### Triggering

| Parameter    | Symbol   | Min | Max | Typ | Unit | Conditions  |
|--------------|----------|-----|-----|-----|------|---|
| Gate current | $I_{GT}$ |     | 350 |     | mA   | $V_D = 6 \text{ V}; R_L = 6 \Omega; T_j = 25^\circ\text{C}$ |
| Gate voltage | $V_{GT}$ |     | 3.5 |     | V    | $V_D = 6 \text{ V}; R_L = 6 \Omega; T_j = 25^\circ\text{C}$ |

### Thermal and mechanical characteristics and ratings

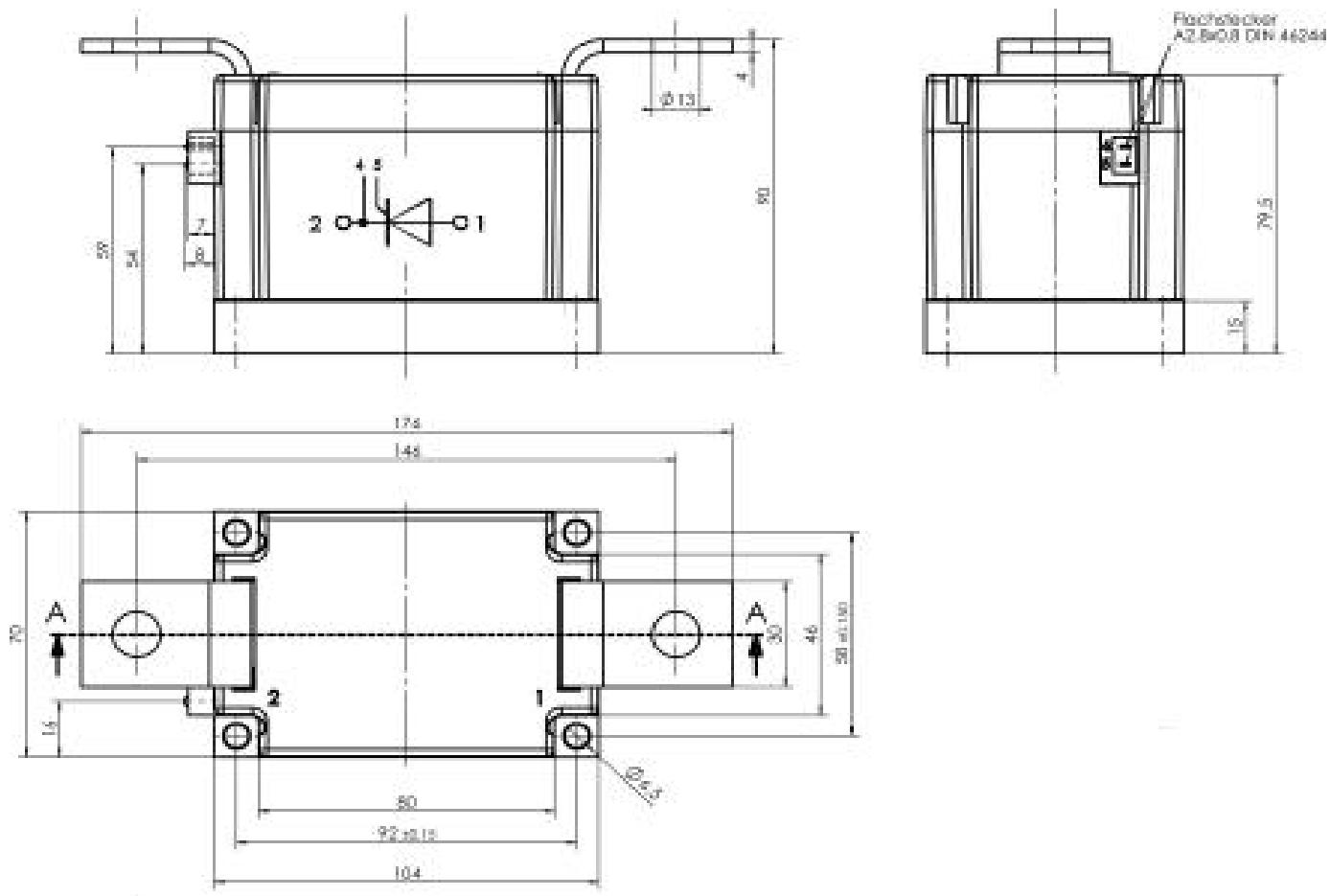
| Parameter                           | Symbol        | Min | Max   | Typ  | Unit | Conditions   |
|-------------------------------------|---------------|-----|-------|------|------|--|
| Operating temperature               | $T_j$         | -40 | 125   |      | °C   |  |
| Storage temperature                 | $T_{stg}$     | -40 | 125   |      | °C   |  |
| Thermal resistance junction to case | $R_{th(j-c)}$ |     | 0.042 |      | °C/W | SIN 180° conduction mounting surfaces smooth, flat and greased |
| Thermal resistance case to sink     | $R_{th(c-s)}$ |     | 0.010 |      | °C/W |  |
| Mounting torque case-heatsink       | $T$           | 4   | 6     |      | N·m  |  |
| Mounting torque busbar-terminals    | $T$           | 12  | 18    |      | N·m  |  |
| Weight                              | $W$           |     |       | 2800 | g    |  |



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### OUTLINE AND DIMENSIONS



(all dimensions in mm)